AD162A Datasheet

Zhuhai Jieli Technology Co.,LTD

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AD162A Features

CPU

- 32bit DSP
- Maximum speed 160MHz
- Interrupts with 8 priority level

Memory

- OTP
- Optional built-in flash memory

Clocks

- On-chip 16 MHz clock
- On-chip 200KHz lower-temperature-drift clock
- 32.768 KHz crystal oscillator

DSP Audio Processing

- Support MP2, MP3, WMA, WAV decoding
- Multi-band DRC limiter
- Multi-band EQ configuration for voice Effects

Audio Codec

- One channels 16-bit DAC, with SNR \geq 93dB
- One channel 24-bit ADC, SNR \geq 85dB
- Audio DAC Sampling rates of 8KHz/11.025KHz/16KHz/22.05KHz/24KHz/32KHz/44.1KHz/48KHz/64KHz/88.2KHz/96KHz are supported
- Audio ADC Sampling rates of 8KHz/11.025KHz/16KHz/22.05KHz/24KHz/32KHz/44.1KHz/48KHz are supported
- Audio DAC support single-ended mode
- Support analog audio input
- Support for driving 16 or 32 ohm speaker

Peripherals

- One full speed USB OTG controller
- One SD host controller for MMC/SD
- Three multi-function 32-bit timers, support capture and PWM mode
- UART0 controller
- The UART1 supports DMA and flow control
- One IIC Master controller
- Two SPI Master / Slaver controller with DMA
- One QDEC interface
- 6-channel 10-bit general purpose ADC
- 4-channel Advance PWM controller
- 10 Individually programmable and multiplexed GPIO pins
- Digital peripheral crossbar
- Up to 9 external interrupt / wake-up source (low power available,can be multiplexed to any I/O)

PMU

- Built-in lithium battery charging manager,up to 120mA charging current
- RTC Alarm Wakeup
- Less than 2uA soft off current
- VPWR range : 4.5V to 6.0V
- VBAT range : 2.2V to 5.0V
- IOVDD range: 2.1V to 3.6V

Packages

SOP16

Temperature

- Operating temperature: -40°C to +85°C
- Storage temperature: -65° C to $+150^{\circ}$ C

Applications

- Audio player
- Microcontrollers



1 Block Diagram

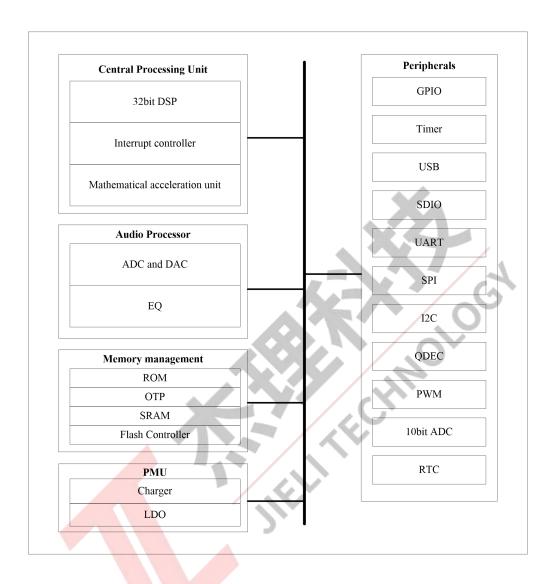


Figure 1-1 AD162A Block Diagram



2 Pin Definition

2.1 Pin Assignment

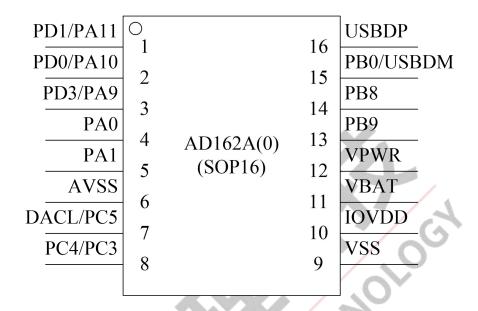


Figure 2-1 AD162A(0) Package Diagram

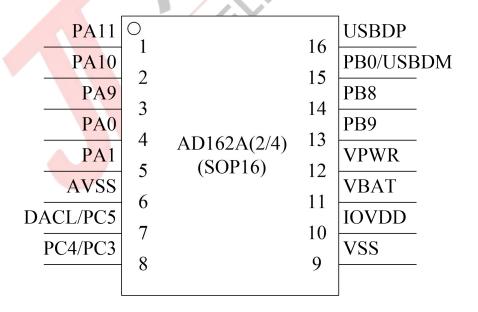


Figure 2-2 AD162A(2/4) Package Diagram



2.2 Pin Description

Table 2-1 AD162A Pin Description

PIN	Name				
NO.	A0	A2/A4	Type	Function	Other Function
	PD1	NC	I/O	GPIO	SFCDO(A):SFC Data Out(A);
1	151	110	1/0	GITO	SPI0DO(A):SPI0 Data Out(A);
1	PA11 I/O		I/O	GPIO	SDCMD(C):SD CMD(C);
			1/0	di io	M_TMR1CK;
	PD0	NC	I/O	GPIO	SFCCLK(A):SFC Clk(A);
	100	110	1/0	GHO	SPI0CLK(A):SPI0 Clk(A);
2					SDDAT(C):SD Data(C);
	PA	.10	I/O	GPIO	ADC4:ADC Input Channel 4;
					PWMCH1L:Motor PWM Channel1(L);
	PD3	NC	I/O	GPIO	SFCCS(A):SFC Chip Select(A);
3	1.03	110	1/0	GHO	SPI0CS(A):SPI0 Chip Select(A);
	PA	19	I/O	GPIO	PWMCH1H:Motor PWM Channel1(H);
					MICLDO:Microphone linear voltage regulator output;
4	P.A	١0	I/O	GPIO	ADC0:ADC Input Channel 0;
7	17	10	1/0	dilo	UART1TXB:Uart1 Data Output(B);
					PWM0:Timer0 PWM Output;
	PA1				MICIN0:MIC0 Input Channe;
5			I/O	GPIO	UART1RXB:Uart1 Data Input(B);
			13		TMR0:Timer0 Clock Input;
6	AV	rss	G		Audio ground;
7	DA	.CL	AO		Left channel audio output;
,	PO	C5	I/O	GPIO	AINR:Right channel analog audio input;
	PC	24 I/O		GPIO	AINL:Left channel analog audio input;
8	r	J4	1/0	GFIO	TMR2:Timer2 Clock Input;
0	D(PC3 I/O		GPIO	SDPG:SD card Power Gate;
	10			dilo	ADC13:ADC Input Channel 13;
9	V	ss 🦳	G		System ground;
10	IOV	'DD	PO	Power supply for GPIO	Built-in linear voltage regulator output;
11	VB	AT	P		Battery interface;
					Charge Power Input;
12	12 VPWR (PP0)		PI	GPIO	UART1TXA:Uart1 Data Output(A);
12			(I/O)	GHO	UART1RXA:Uart1 Data Input(A);
				CAP1:Timer1 Capture;	
13	PB9 I/O GPIO		GPIO	ROSCI_32K:32.768KHz crystal oscillator input;	
13)	1/0	Grio	CLKOUT2:Clock Out2;
					ROSCO_32K:32.768KHz crystal oscillator output;
14	PI	38	I/O	GPIO	ADC10:ADC Input Channel 10;
					CLKOUT1:Clock Out1;



	PB0	I/O	GPIO	ADC5:ADC Input Channel 5;
				SPI1DO(A):SPI1 Data Out(A);
15	UDBDM	I/O	USB Negative Data	IIC0_SDA(A):IIC0 SDA(A);
	UDBDM	1/0	(pull down)	UART0RXA:Uart0 Data Input(A);
				ADC15:ADC Input Channel 15;
				SPI1CLKA:SPI1 Clk(A);
16	USBDP	I/O	USB Positive Data	IIC0_SCL(A):IIC0 SCL(A);
10	10 USBDP	1/0	(pull down)	UART0TXA:Uart0 Data Output(A);
				ADC14:ADC Input Channel 14;

Pin Type	Description	Pin Type	Description
P	Power	I/O	Input or Output
PI	Power Input	I	Input
PO	Power Output	0	Output
AO	Analog Output	G	Ground



3 Electrical Characteristics

3.1 Absolute Maximum Ratings

Table 3-1

Symbol	Parameter	Min	Max	Unit
Topt	Operating temperature	-40	+85	°C
Tstg	Storage temperature	-65	+150	°C
VBAT	Supply Voltage	-0.3	5.0	V
VPWR	Charger Voltage	-0.3	6.0	V
$V_{\rm IOVDD}$	Voltage applied at IOVDD	-0.3	3.6	V
$ m V_{GPIO}$	Voltage applied to GPIO	-0.3	IOVDD+0.3	V

Note: The chip can be damaged by any stress in excess of the absolute maximum ratings listed below

3.2 PMU Characteristics

Table 3-2

Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
VBAT	Voltage Input	2.2	3.7	5.0	V	"
VPWR	Charger supply Voltage	4.5	5.0	6.0	V	-
IOVDD	Voltage output	2.1	3.0	3.6	V	VBAT = 4.2V, 10mA loading
10 V DD	Loading current			100	mA	IOVDD=3.3V@VBAT = 3.6V
$V_{ m LVD}$	Voltage input	2.1	2.8	2.8	V	Low-Voltage Detection of IOVDD

3.3 Battery Charge

Table 3-3

Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
V_{PWR}	Charge Input Voltage Range	4.5	5	6.0	V	_
V	Pottows Charge Termination Voltage	4.15	4.2	4.25	V	VPWR>4.5V
V BAT Float	V _{BAT Float} Battery Charge Termination Voltage		4.35	4.40	V	VPWR>4.65V
I_{BAT}	Fast Charge Current	20	_	120	mA	VBAT=4.0V@VPWR=5.0V
I _{END}	Charge Termination Current Threshold	2	_	12	mA	CHG_IIFULL_S==0,1
V_{Trikl}	Trickle Charge Voltage	_	3.0	_	V	VPWR>4.5V
I_{Trikl}	Trickle Charge Current	2	_	12	mA	$V_{BAT} < V_{Trikl}$



3.4 IO Input/Output Electrical Logical Characteristics

Table 3-4

GPIO input cha	racteristics					
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
$ m V_{IL}$	Low-Level Input Voltage	-0.3	_	0.3* IOVDD	V	IOVDD = 3.0V
$ m V_{IH}$	High-Level Input Voltage	0.7* IOVDD	_	IOVDD+0.3	V	IOVDD = 3.0V
GPIO output ch	aracteristics					
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
$ m V_{OL}$	Low-Level Output Voltage	_	_	0.1* IOVDD	V	IOVDD = 3.0V
$ m V_{OH}$	High-Level Output Voltage	0.9* IOVDD	_	-	V	IOVDD = 3.0V

3.5 Internal Resistor Characteristics

Table 3-5

Port	Drive Current	Internal Pull-Up Resistor	Internal Pull-Down Resistor	Comment
PA0,PA1 PA9~PA11 PB0,PB8,PB9 PC3~PC5 PD0,PD1,PD3	2mA(HD1,HD0==0,0) 5.6mA(HD1,HD0==0,1) 18mA(HD1,HD0==1,0) 30mA(HD1,HD0==1,1)	10K	10K	USBDM,USBDP default pull down Internal pull-up/pull-down
PP0(VPWR)	1.4mA	10K	10K	resistance accuracy ±20%
USBDP	27mA	1.5K	15K	
USBDM	Z/IIIA	180K	15K	

3.6 Audio DAC Characteristics

Table 3-6

Parameter	MODE	Min	Тур	Max	Unit	Test Conditions
Frequency Response		20	_	20K	Hz	
Output Swing	Single-ended	_	750	_	mVrms	1KHz/0dB
THD+N	Single-ended	_	-80	_	dB	10k ohm loading
S/N	Single-ended	_	93	_	dB	With A-Weighted Filter
Dynamic Range	Single-ended	_	93	_	dB	IOVDD>2.7V
Noise Floor	Single-ended	_	18	_	uVrms	
						10KHz/0dB
Crosstalk	Single-ended	_	-93	_	dB	10k ohm loading
						IOVDD>2.7V



3.7 Audio ADC Characteristics

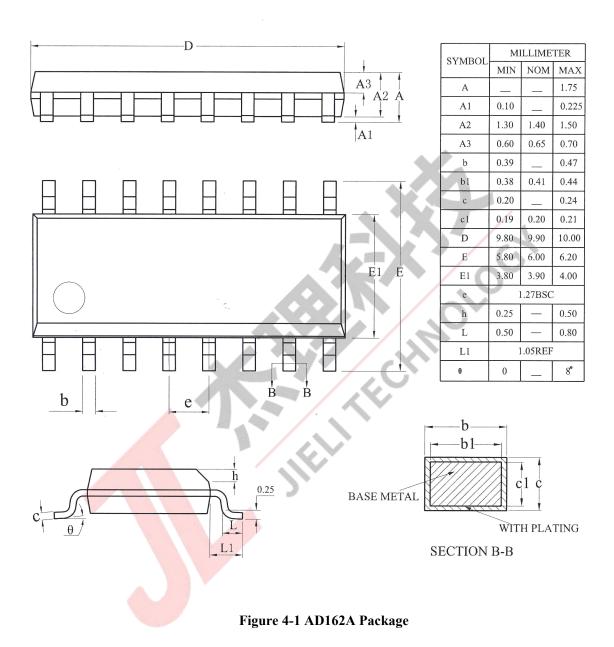
Table 3-7

Parameter	MODE	Min	Тур	Max	Unit	Test Conditions
				_	dB	Fsample=44.1KHz,Gain=-2dB
			0.5			Fin=1KHz @1Vpp
		_	85			NO A-wt 20Hz-20KHz
Dynamic Range	Single-ended					IOVDD>2.7V
Dynamic Kange	Single-chided					Fsample=44.1KHz,Gain=14dB
			72		dB	Fin=1KHz @160mVpp
		_	12	_	ub	NO A-wt 20Hz-20KHz
					9	IOVDD>2.7V
						Fsample=44.1KHz,Gain=-2dB
	Single-ended	-	85	_	dB	Fin=1KHz @1Vpp
						NO A-wt 20Hz-20KHz
S/N				7		IOVDD>2.7V
3/11			72	X	dB	Fsample=44.1KHz,Gain=14dB
						Fin=1KHz @160mVpp
						NO A-wt 20Hz-20KHz
						IOVDD>2.7V
						Fsample=44.1KHz,Gain=-2dB
			-78		dB	Fin=1KHz @1Vpp
		-	170	~~	uD	NO A-wt 20Hz-20KHz
THD+N	Single-ended					IOVDD>2.7V
THD+N	Single-ended					Fsample=44.1KHz,Gain=14dB
			-70		AD	Fin=1KHz @160mVpp
		_	-70	_	dB	NO A-wt 20Hz-20KHz
			1697			IOVDD>2.7V



4 Package Information

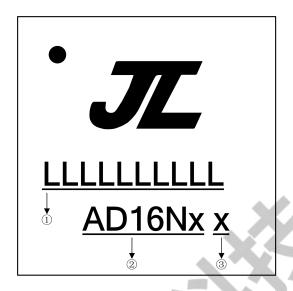
4.1 SOP16



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5 IC Marking Information



- ① LLLLLLLLL: Production Batch
- ② AD16Nx: Chip Model
- 3 Built-in flash size
 - 0: No Flash Memory
 - 2: 2Mbit Flash
 - 4: 4Mbit Flash
 - 8: 8Mbit Flash
 - 6: 16Mbit Flash
 - 3: 32Mbit Flash



6 Solder-Reflow Condition

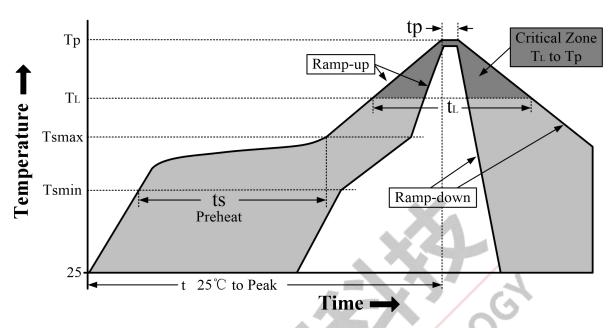


Figure 6-1 Classification Reflow Profile

Classification Profiles

Table 6-1

	Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
	Temperature Min (T _{smin})	100 °C	150 °C
Preheat/	Temperature Max (T _{smax})	150 °C	200 ℃
Soak	Time (ts) from (T _{smin} to T _{sma} x)	60-120 seconds	60-180 seconds
Average ra	amp-up rate $(T_{smax} \text{ to } T_p)$	3 °C/second max	3 °C/second max
Liquidous temperature (T _L)		183 °C	217 ℃
Time (t _L) 1	maintained above T _L	60-150 seconds	60-150 seconds
Peak pack	age body temperature (T _p)	See Table 6-2.	See Table 6-3.
Time within 5°C of actual Peak Temperature (tp)		10-30 seconds	20-40 seconds
Ramp-down rate (T _p to T _L)		6 °C/second max.	6 °C/second max.
Time 25	C to peak temperature	6 minutes max.	8 minutes max.

Note 1: All temperatures refer to topside of the package, measured on the package body surface.

Note 2: Time within 5° C of actual peak temperature (tp) specified for the reflow profiles is a "supplier" minimum and "user" maximum.

SnPb - Classification Temperature

Table 6-2

Package	Volume mm ³	Volume mm ³		
Thickness	< 350	≥ 350		
<2.5 mm	240 +0/-5 °C	225 +0/-5 °C		
≥ 2.5 mm	225 +0/-5 °C	225 +0/-5 °C		



Pb-free - Classification Temperature Table 6-3

Package	Volume mm ³	Volume mm ³	Volume mm ³
Thickness	< 350	350 - 2000	> 2000
< 1.6mm	260 ℃	260 ℃	260 ℃
1.6 mm - 2.5mm	260 ℃	250 ℃	245 ℃
> 2.5mm	250 ℃	245 ℃	245 ℃





7 Revision History

Date	Revision	Description
2022.09.16	V1.0	Initial Release.
		Update Pin Definition.
2022.11.28	V1.1	Update VPWR,VBAT range.
		Update DAC,ADC Test Conditions.
2023.03.22	V1.2	Features modification

